



CPH3338 — P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-3.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-14	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm ² X0.8mm)	1.0	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-2A	2.4	4		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-2A, V _{GS} =-10V		57	74	mΩ
	R _{DS(on)2}	I _D =-1A, V _{GS} =-4.5V		101	141	mΩ
	R _{DS(on)3}	I _D =-1A, V _{GS} =-4V		118	165	mΩ
Input Capacitance	C _{iss}	V _{DS} =-10V, f=1MHz		566		pF
Output Capacitance	C _{oss}	V _{DS} =-10V, f=1MHz		101		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =-10V, f=1MHz		84		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		11		ns
Rise Time	t _r	See specified Test Circuit.		13		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		49		ns
Fall Time	t _f	See specified Test Circuit.		36		ns

Marking : YN

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CPH3338

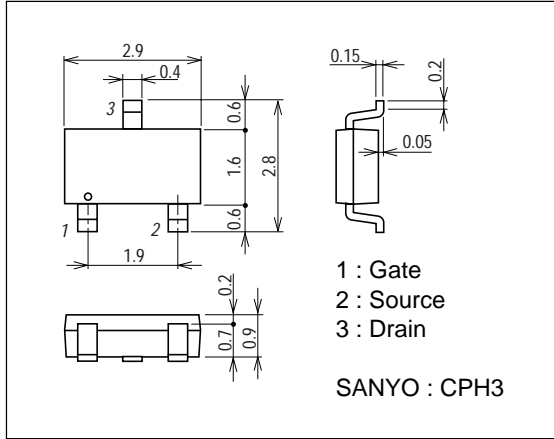
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	$V_{DS}=-10V, V_{GS}=-10V, I_D=-3.5A$		11.7		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-10V, V_{GS}=-10V, I_D=-3.5A$		2.04		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-10V, V_{GS}=-10V, I_D=-3.5A$		2.64		nC
Diode Forward Voltage	V_{SD}	$I_S=-3.5A, V_{GS}=0$		-0.86	-1.2	V

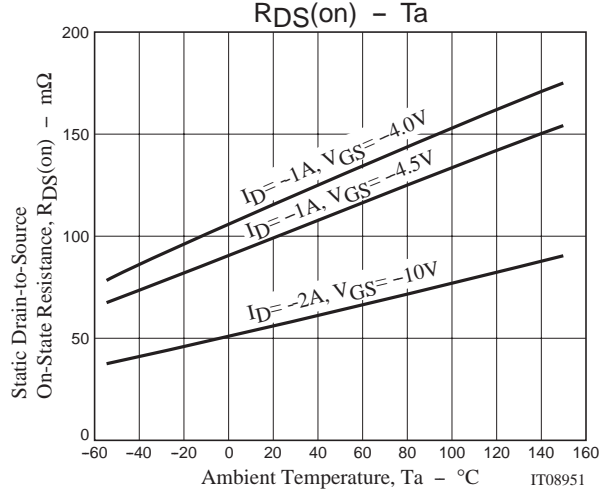
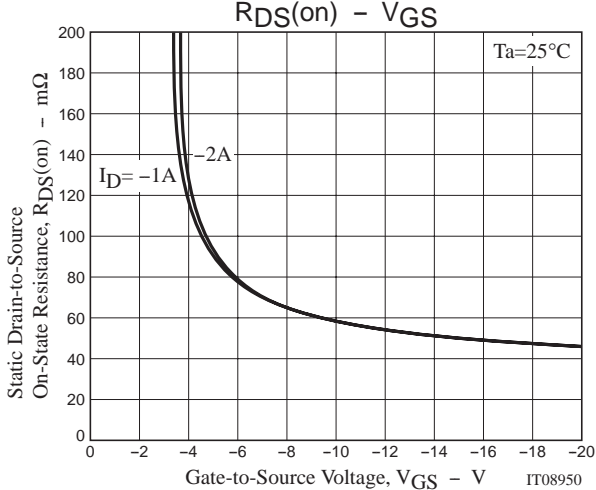
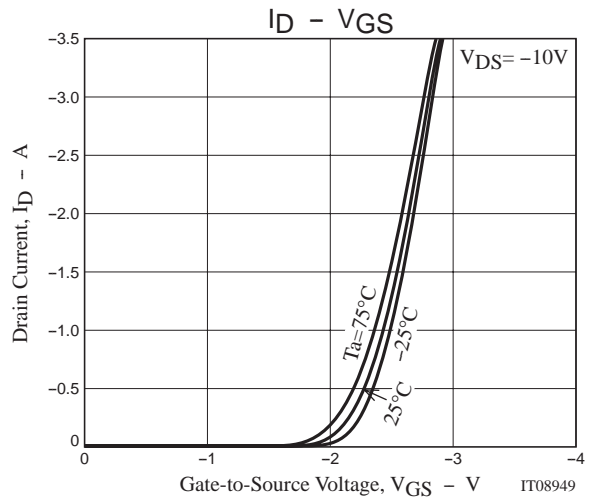
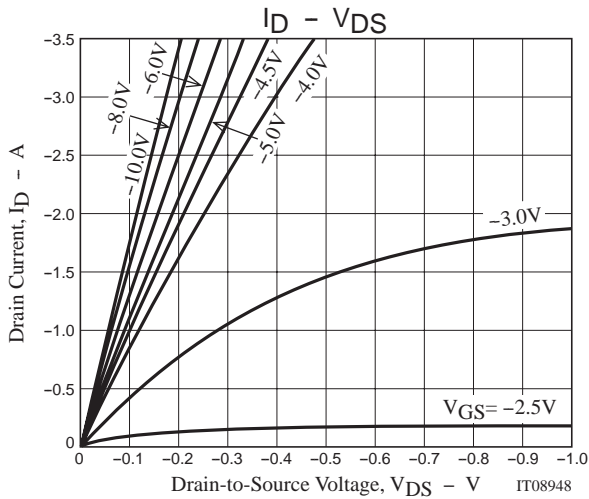
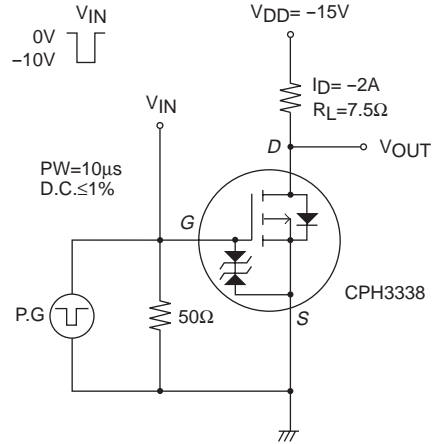
Package Dimensions

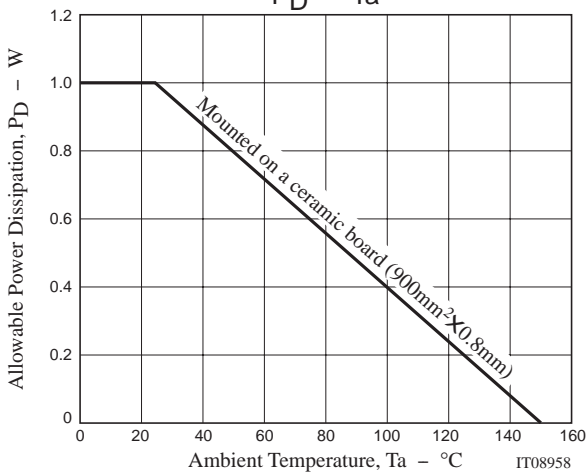
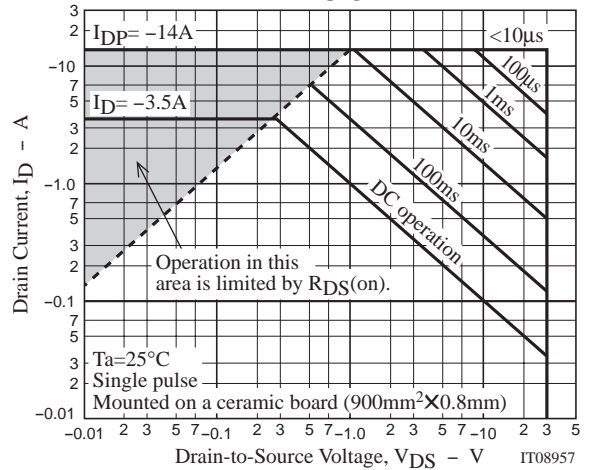
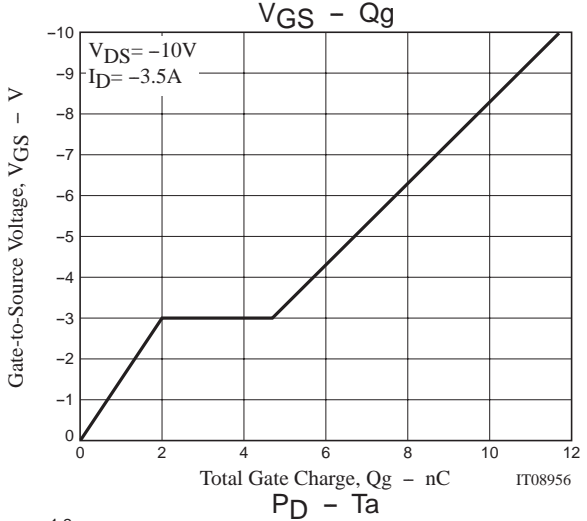
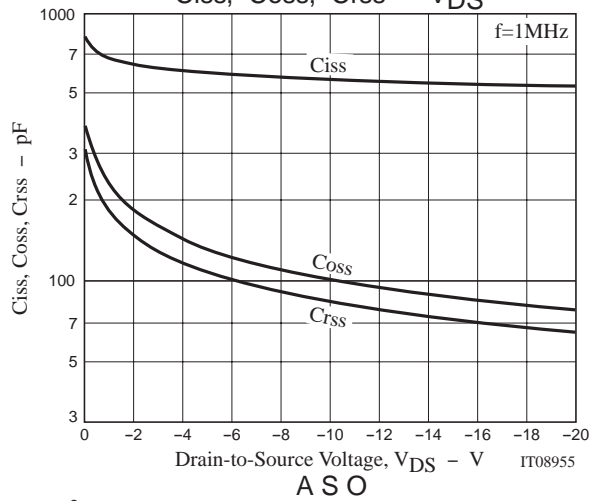
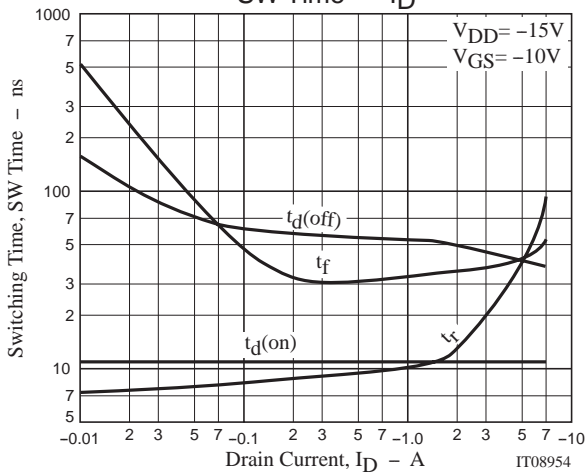
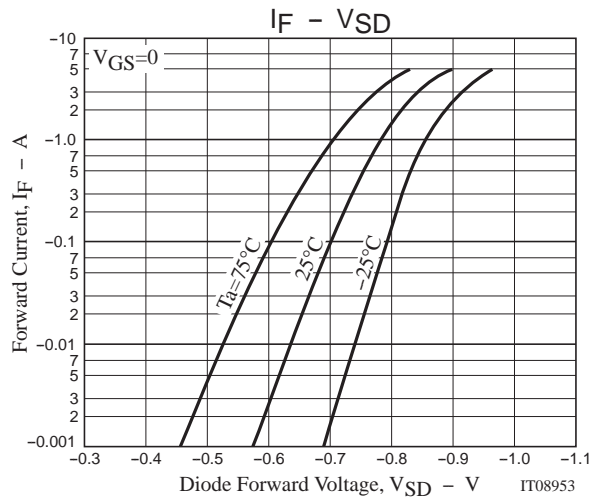
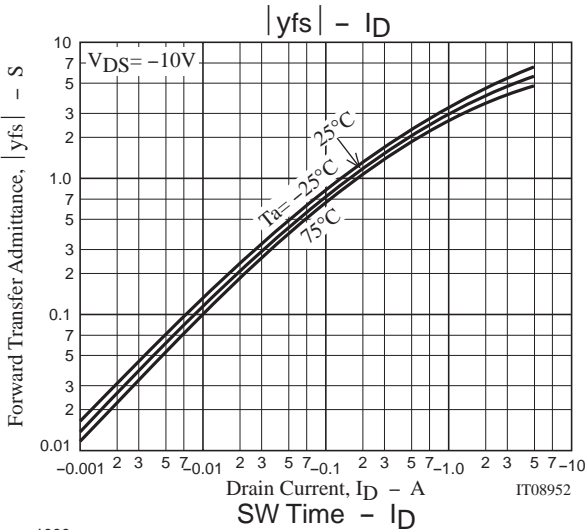
unit : mm

2152A



Switching Time Test Circuit





Note on usage : Since the CPH3338 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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